

Dynamic Engineers Inc.

2550 Gray Falls Dr., Suite#128, Houston, TX, 77077 USA TEL: 1-281-870-8822 EMAIL:Sales@DynamicEng.com

OCXO3182-X39_Rev.4 Ultra-miniature DOCXO @10MHz

Features

Ultra Miniature Packaging High Stability - to \pm 2x10⁻¹⁰ over (-30 to +70)°C Low Aging - to \pm 2x10⁻¹⁰/day, 3x10⁻⁸/year Low Phase Noise level (-163 dBc/Hz, TYP, floor)

Typical Applications

Rubidium Standard Replacement GPS Receivers Instrumentation Stratum 2 Clock Systems

Packaging type R: 20.4 x 20.4 x 13.8 mm

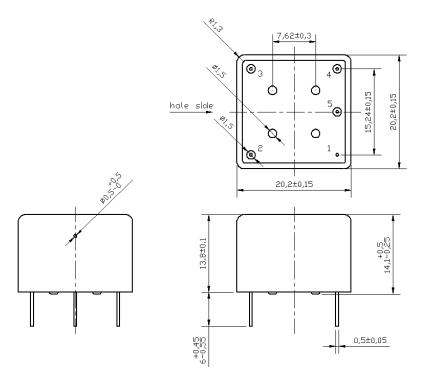


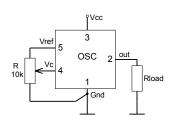


Description

The OCXO3182 series use combines advantageous of the double-oven and internal heatedresonator technologies(IHR) resulting in smallest in the world volume (6 ccm) and less than 1W power consumption at 0.2 ppb tempeature stability and 0.2 ppb/day aging. The OCXO3182 oscillators are excellent to use in Stratum II clock system, instrumentations, and other high-end applications. The double-oven OCXOs are produced for operational frequency range from 8 to 100MHz.

Physical Dimensions & Pin Connections





Pin	Signal		
1	GND		
2	RF Out		
3	+V Supply		
4	Electrical tuning		
5	Reference voltage		



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Specification

#	OCX	О	Sym.	Condition		Value		Unit	Included in the
	Specific	ation			Min.	Тур.	Max.		test data
1.1	Nominal Freque	ency	f_0			10.000000		MHz	
1.2	Initial tolerance		$(f-f_0)/f_0$	at $+25^{\circ}$ C, $V_c=V_{c0}$	-0.1		0.1	ppm	+
	RF output								
2.1	Wave form					Sine-wave			
2.2	Level		L		+6			dBm	+
2.3	Load		R_{L}		45	50	55	Ohm	
2.4	Harmonics level						-25	dBc	+
Frequency control									
3.1	Input resistance		Rin			11		kΩ	
3.2	Control voltage		V _c		0		4.2	V	
3.3	Preset control vo	oltage	V_{c0}	disconnected Vc pin	1.9	2.1	2.3	V	
3.4	Slope					Positive			
3.5			$(f_L-f)/f$	$V_c=0 V$			-0.35	ppm	+
	Pull range		(f-f)/f	$V_c = V_{c0}$		0		ppm	
3.6			(f _H - f)/f	$V_c = V_{ref}$	0.35			ppm	+
3.7	Reference voltag		V_{ref}		4.1	4.2	4.3	V	
3.8	Out. resistance of	fV_{ref}				91		Ohm	
	Power supply								
4.1	Voltage		Vcc		4.75	5	5.25	V	
4.2	Warm-up curren			Vcc=5V			850	mA	+
4.3	Continuous curr	ent		at +25°C, Vcc=5V, still air			250	mA	+
4.4	Warm-up time		t_{up}	to $\Delta f/f=1e-7$, at $+25$ °C,			180	sec.	
				ref. to 30 min.					
	Frequency stabil	ity				,			·
5.1	vs. temperature			ref 25°C			±3	ppb	plot
5.2	vs. supply voltag	ge		ref Vcc typ.			±0.3	ppb	
				at 1 Hz offset		-95			
	SSB Phase Noise			at 10 Hz offset		-130		dBc/Hz +*	
6.1				at 100 Hz offset		-150			+*
0.1			-	at 1 kHz offset		-162			'
				at 10 kHz offset		-168			
		1		at 100 kHz offset		-168		1	+**
7.1	Aging	per day per year	+	after 30 days of operation			±0.2	ppb	+**
¥ 1 ^	0/ 6 1 4: 7.6	1 2	. , ,	14. 20			±30	ppb	
* 10	% of production LC aily and Yearly Proj	or quantitiected Aging F	ies greater than Rates	or equal to 20 pcs					
	mum ratings, envi			ditions.					
Power voltage			-0.5 to 6 V						
Control voltage		-1.0 to 9.0 V	V						
	ating temperature ra	inge		35°C (-55°C to -40°C operable)					
Storage temperature range			-60°C to +9						
Hamidita		Harmaticall							

Power voltage	-0.5 to 6 V
Control voltage	-1.0 to 9.0 V
Operating temperature range	-40°C to +85°C (-55°C to -40°C operable)
Storage temperature range	-60°C to +90°C
Humidity	Hermetically sealed
Mechanical shock	Per MIL-STD-202, 30G, 11ms
Vibration	Per MIL-STD-202, 10G to 500 Hz
Soldering conditions	260°C, 10s